128K × 8 HIGH SPEED CMOS STATIC RAM

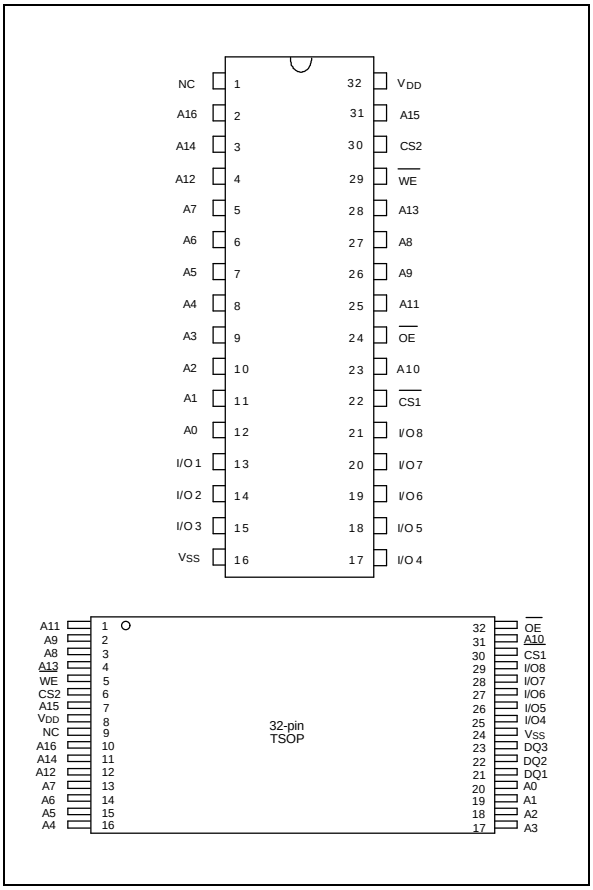
GENERAL DESCRIPTION

The W24010A is a high speed, low power CMOS static RAM organized as 131072 × 8 bits that operates on a single 5-volt power supply. This device is manufactured using Winbond's high performance CMOS technology, which can meet the industrial grade requirement.

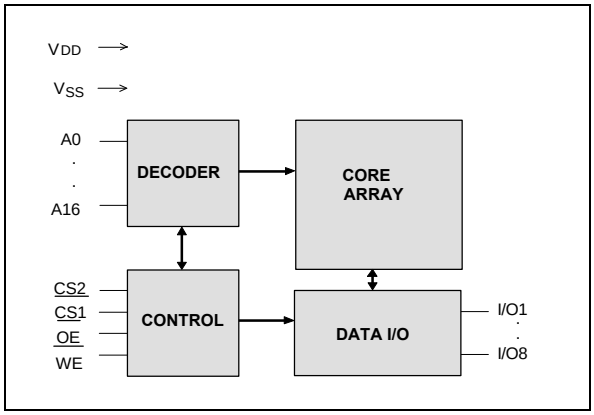
FEATURES

- Meet industrial grade: -40 to 85° C
- High speed access time: 12/15 nS (max.)
- Low power consumption:
  – Active: 600 mW (typ.)
- Single +5V power supply
- Fully static operation
- All inputs and outputs directly TTL compatible
- Three-state outputs
- Available packages: 32-pin 300 mil SOJ, 400 mil SOJ, skinny DIP and standard type one TSOP (8 mm × 20 mm)

PIN CONFIGURATIONS



BLOCK DIAGRAM



PIN DESCRIPTION

SYMBOL	DESCRIPTION
A0–A16	Address Inputs
I/O1–I/O8	Data Inputs/Outputs
$\overline{CS1}$, CS2	Chip Select Inputs
$\overline{WE}$	Write Enable Input
$\overline{OE}$	Output Enable Input
VDD	Power Supply
VSS	Ground
NC	No Connection

TRUTH TABLE

$\overline{CS1}$	CS2	$\overline{OE}$	$\overline{WE}$	MODE	I/O1- I/O8	V_{DD} CURRENT
H	X	X	X	Not Selected	High Z	I_{SB}, I_{SB1}
X	L	X	X	Not Selected	High Z	I_{SB}, I_{SB1}
L	H	H	H	Output Disable	High Z	I_{DD}
L	H	L	H	Read	Data Out	I_{DD}
L	H	X	L	Write	Data In	I_{DD}

DC CHARACTERISTICS

Absolute Maximum Ratings

PARAMETER	RATING	UNIT
Supply Voltage to V_{SS} Potential	-0.5 to +7.0	V
Input/Output to V_{SS} Potential	-0.5 to V_{DD} +0.5	V
Allowable Power Dissipation	1.0	W
Storage Temperature	-65 to +150	°C
Operating Temperature	-40 to +85	°C

Note: Exposure to conditions beyond those listed under Absolute Maximum Ratings may adversely affect the life and reliability of the device.

Operating Characteristics

(V_{DD} = 5V ±10%, V_{SS} = 0V, T_A = -40 to 85° C)

PARAMETER	SYM.	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Input Low Voltage	V_{IL}	-	-0.5	-	+0.8	V
Input High Voltage	V_{IH}	-	+2.2	-	V_{DD} +0.5	V
Input Leakage Current	I_{LI}	V_{IN} = V_{SS} to V_{DD}	-10	-	+10	µA
Output Leakage Current	I_{LO}	$V_{I/O}$ = V_{SS} to V_{DD} $\overline{CS1}$ = V_{IH} (min.) or CS2 = V_{IL} (max.) or $\overline{OE}$ = V_{IH} (min.) or $\overline{WE}$ = V_{IL} (max.)	-10	-	+10	µA
Output Low Voltage	V_{OL}	I_{OL} = +8.0 mA	-	-	0.4	V
Output High Voltage	V_{OH}	I_{OH} = -4.0 mA	2.4	-	-	V
Operating Power Supply Current	I_{DD}	$\overline{CS1}$ = V_{IL} (max.), CS2 = V_{IH} (min.) I/O = 0 mA. Cycle = mim. Duty = 100%	-	-	200	mA
Standby Power Supply Current	I_{SB}	$\overline{CS1}$ = V_{IH} (min.), or CS2 = V_{IL} (max.)	-	-	30	mA
	I_{SB1}	$\overline{CS1}$ ≥ V_{DD} -0.2V or CS2 ≤ 0.2V	-	-	10	mA

Note: Typical characteristics are at V_{DD} = 5V, T_A = 25° C.

CAPACITANCE

(V_{DD} = 5V, T_A = 25° C, f = 1 MHz)

PARAMETER	SYM.	CONDITIONS	MAX.	UNIT
Input Capacitance	C_{IN}	V_{IN} = 0V	8	pF
Input/Output Capacitance	$C_{I/O}$	V_{OUT} = 0V	10	pF

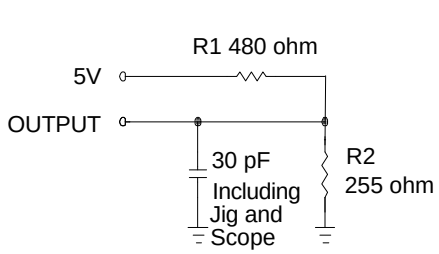
Note: These parameters are sampled but not 100% tested.

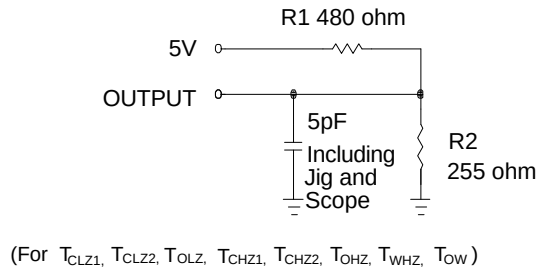
AC CHARACTERISTICS

AC Test Conditions

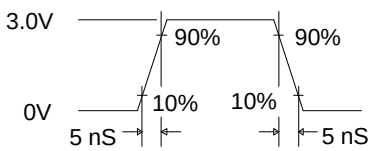
PARAMETER	CONDITIONS
Input Pulse Levels	0V to 3V
Input Rise and Fall Times	5 nS
Input and Output Timing Reference Level	1.5V
Output Load	C_L = 30 pF, I_{OH}/I_{OL} = -4 mA/8 mA

AC Test Loads and Waveform





(For T_{CLZ1}, T_{CLZ2}, T_{OLZ}, T_{CHZ1}, T_{CHZ2}, T_{OHZ}, T_{WHZ}, T_{OW})



AC Characteristics, continued

(V_{DD} = 5V ±10%, V_{SS} = 0V, T_A = -40 to 85° C)

Read Cycle

PARAMETER		SYM.	W24010A-12l		W24010A-15l		UNIT
			MIN.	MAX.	MIN.	MAX.	
Read Cycle Time		T_{RC}	12	-	15	-	nS
Address Access Time		T_{AA}	-	12	-	15	nS
Chip Select Access Time	$\overline{CS1}$	T_{ACS1}	-	12	-	15	nS
	CS2	T_{ACS2}	-	12	-	15	nS
Output Enable to Output Valid		T_{AOE}	-	6	-	7	nS
Chip Selection to Output in Low Z	$\overline{CS1}$	T_{CLZ1}*	3	-	3	-	nS
	CS2	T_{CLZ2}*	3	-	3	-	nS
Output Enable to Output in Low Z		T_{OLZ}*	0	-	0	-	nS
Chip Deselection to Output in	$\overline{CS1}$	T_{CHZ1}*	-	6	-	7	nS
High Z	CS2	T_{CHZ2}*	-	6	-	7	nS
Output Disable to Output in High Z		T_{OHZ}*	-	6	-	7	nS
Output Hold from Address Change		T_{OH}	3	-	3	-	nS

* These parameters are sampled but not 100% tested.

Write Cycle

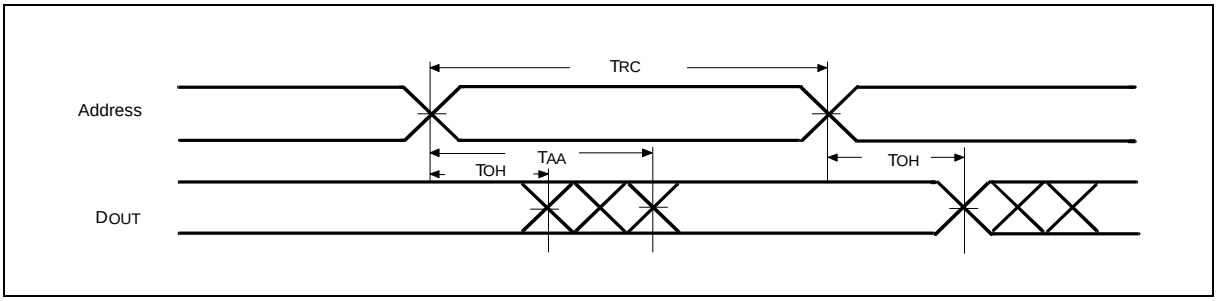
PARAMETER		SYM.	W24010A-12l		W24010A-15l		UNIT
			MIN.	MAX.	MIN.	MAX.	
Write Cycle Time		T_{WC}	12	-	15	-	nS
Chip Selection to End of Write	$\overline{CS1}$	T_{CW1}	10	-	13	-	nS
	CS2	T_{CW2}	10	-	13	-	nS
Address Valid to End of Write		T_{AW}	10	-	13	-	nS
Address Setup Time		T_{AS}	0	-	0	-	nS
Write Pulse Width		T_{WP}	10	-	10	-	nS
Write Recovery Time	$\overline{CS1}$, $\overline{WE}$	T_{WR1}	0	-	0	-	nS
	CS2	T_{WR2}	0	-	0	-	nS
Data Valid to End of Write		T_{DW}	7	-	9	-	nS
Data Hold from End of Write		T_{DH}	0	-	0	-	nS
Write to Output in High Z		T_{WHZ}*	-	7	-	8	nS
Output Disable to Output in High Z		T_{OHZ}*	-	7	-	8	nS
Output Active from End of Write		T_{OW}	0	-	0	-	nS

* These parameters are sampled but not 100% tested.

TIMING WAVEFORMS

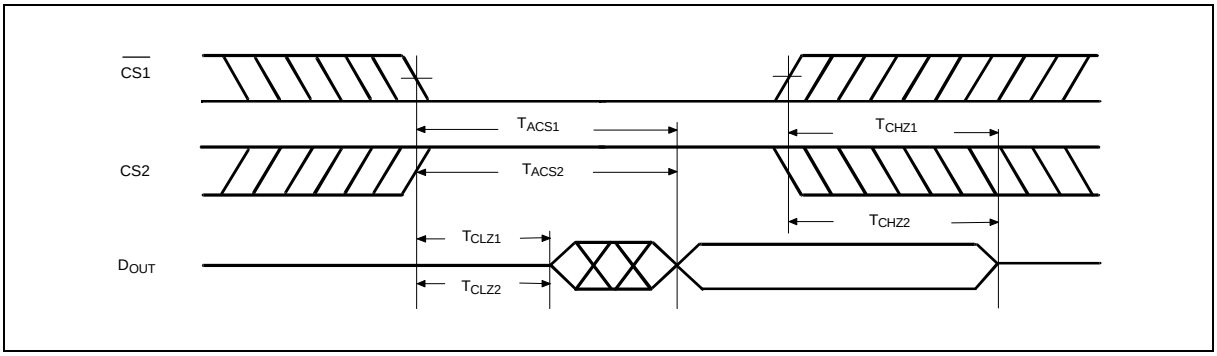
Read Cycle 1

(Address Controlled)



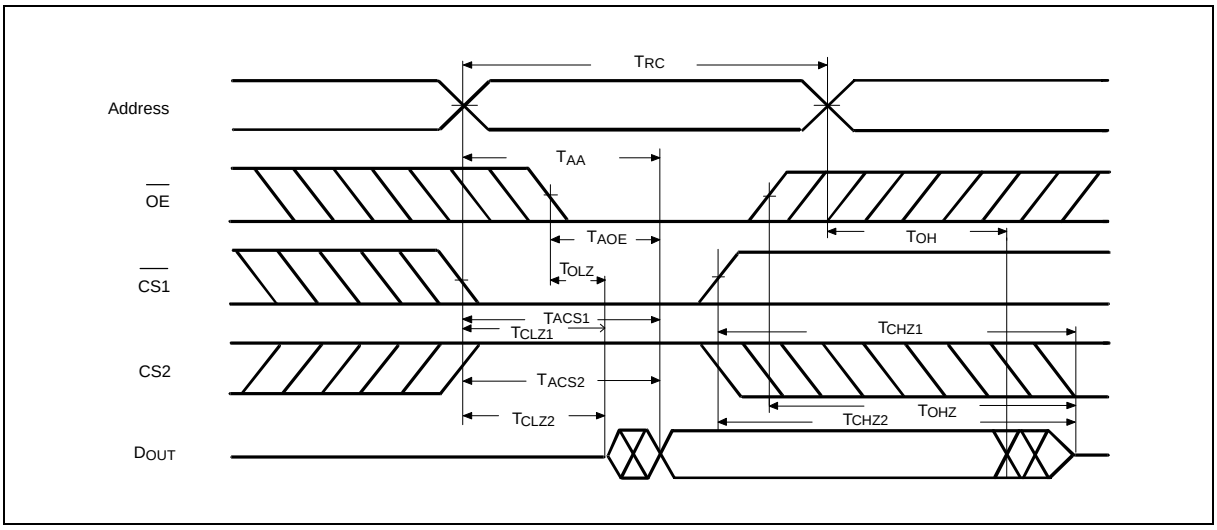
Read Cycle 2

(Chip Select Controlled)



Read Cycle 3

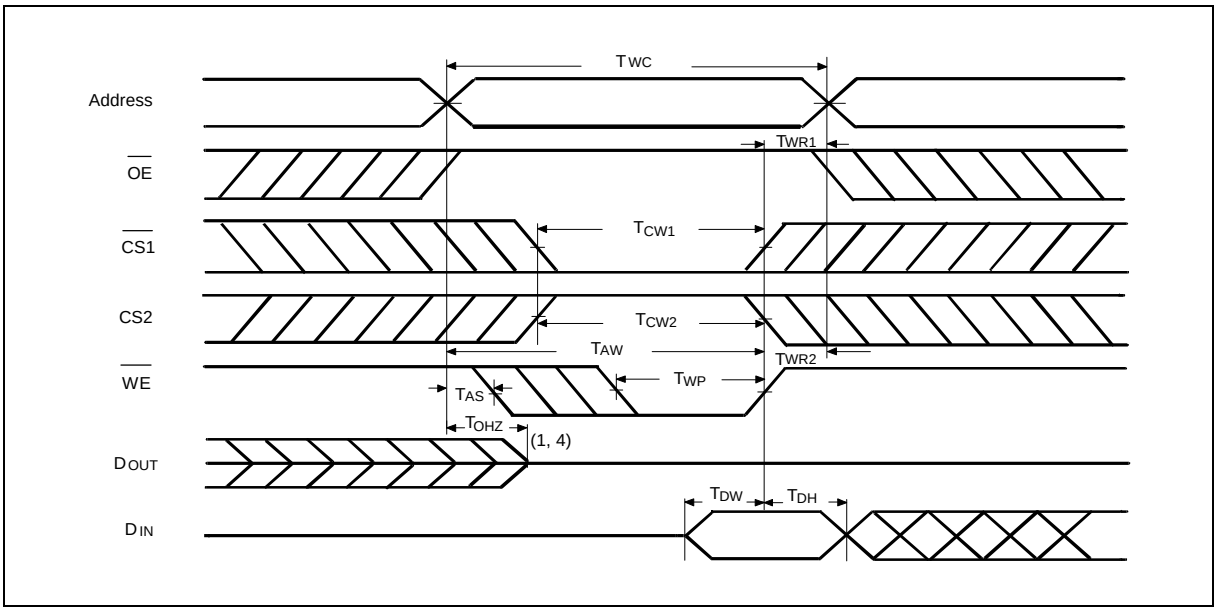
(Output Enable Controlled)



Timing Waveforms, continued

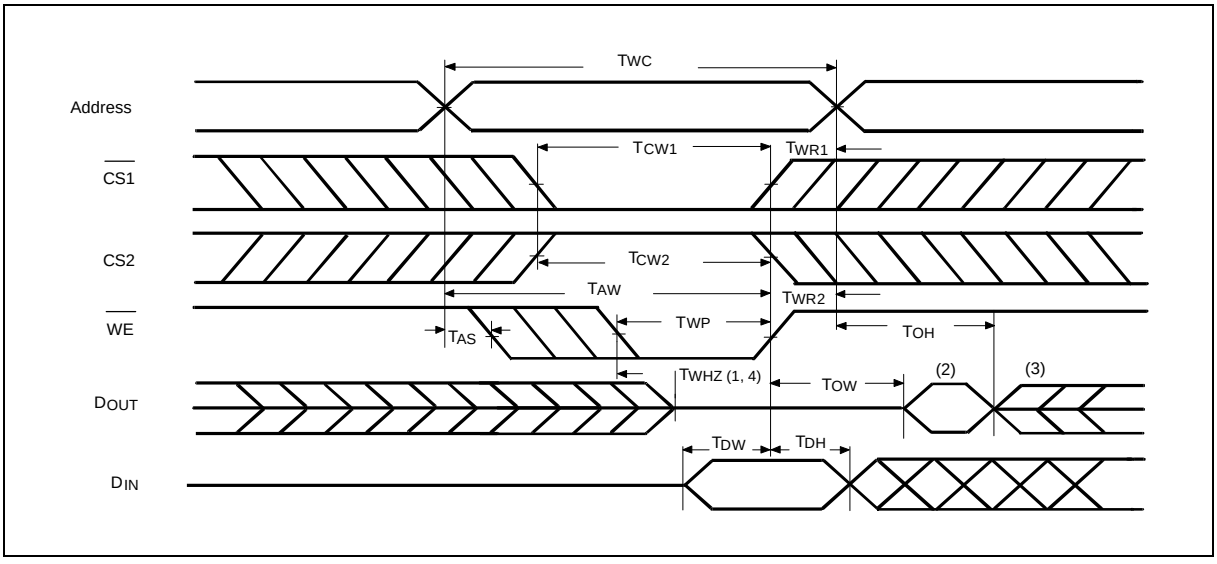
Write Cycle 1

($\overline{OE}$ Clock)



Write Cycle 2

($\overline{OE}$ = VIL Fixed)



Notes:

1. During this period, I/O pins are in the output state, so input signals of opposite phase to the outputs should not be applied.
2. The data output from DOUT are the same as the data written to DIN during the write cycle.
3. Dout provides the read data for the next address.
4. Transition is measured ±500 mV from steady state with CL = 5 pF. This parameter is guaranteed but not 100% tested.

ORDERING INFORMATION

PART NO.	ACCESS TIME (nS)	OPERATING CURRENT MAX. (mA)	STANDBY CURRENT MAX. (mA)	PACKAGE
W24010AK-12I	12	200	10	300 mil skinny DIP
W24010AK-15I	15	200	10	300 mil skinny DIP
W24010AJ-12I	12	200	10	300 mil SOJ
W24010AJ-15I	15	200	10	300 mil SOJ
W24010AI-12I	12	200	10	400 mil SOJ
W24010AI-15I	15	200	10	400 mil SOJ
W24010AT-12I	12	200	10	Standard type one TSOP
W24010AT-15I	15	200	10	Standard type one TSOP

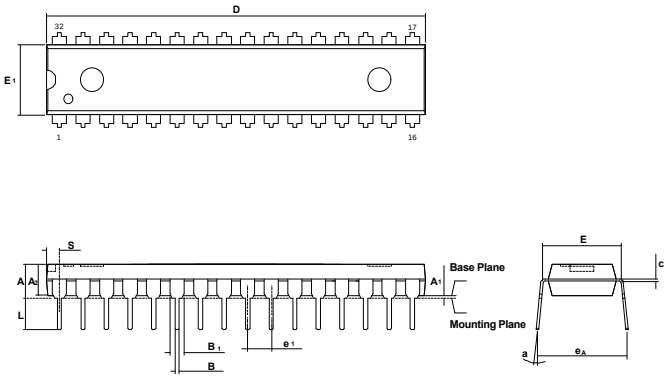
Notes:

1. Winbond reserves the right to make changes to its products without prior notice.
2. Purchasers are responsible for performing appropriate quality assurance testing on products intended for use in applications where personal injury might occur as a consequence of product failure.

Winbond Electronics Corp.

PACKAGE DIMENSIONS

32-pin P-DIP Skinny (300 mil)

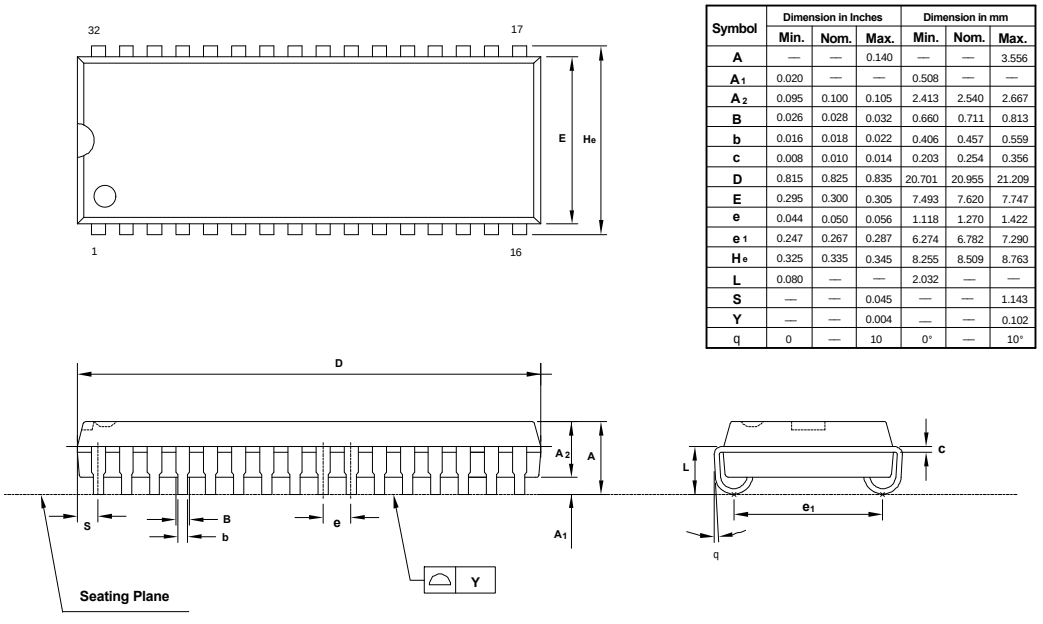


Symbol	Dimension in Inches			Dimension in mm		
	Min.	Nom.	Max.	Min.	Nom.	Max.
A	—	—	0.200	—	—	5.08
A_1	0.015	—	—	0.38	—	—
A_2	0.145	0.150	0.155	3.68	3.81	3.94
B	0.016	0.018	0.022	0.41	0.46	0.56
B_1	0.058	0.060	0.064	1.47	1.52	1.63
c	0.008	0.010	0.014	0.20	0.25	0.36
D	—	1.60	1.62	—	40.64	41.15
E	0.295	0.315	0.335	7.49	8.00	8.50
E_1	0.286	0.290	0.294	7.26	7.36	7.46
e_1	0.090	0.100	0.110	2.29	2.54	2.79
L	0.120	0.130	0.140	3.05	3.30	3.56
a	0	—	15	0°	—	15°
e_A	0.430	0.450	0.470	10.92	11.43	11.94
S	—	—	0.065	—	—	1.65

Notes:

1. Dimension D Max. & S include mold flash or tie bar burrs.
2. Dimension E1 does not include interlead flash.
3. Dimension D & E1 include mold mismatch and are determined at the mold parting line.
4. Dimension B1 does not include dambar protrusion/intrusion.
5. Controlling dimension: Inches.
6. General appearance spec. should be based or final visual inspection spec.

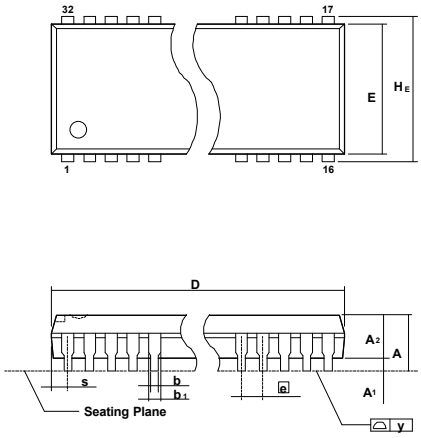
32-pin SOJ (300 mil)



Symbol	Dimension in Inches			Dimension in mm		
	Min.	Nom.	Max.	Min.	Nom.	Max.
A	—	—	0.140	—	—	3.556
A_1	0.020	—	—	0.508	—	—
A_2	0.095	0.100	0.105	2.413	2.540	2.667
B	0.026	0.028	0.032	0.660	0.711	0.813
b	0.016	0.018	0.022	0.406	0.457	0.559
c	0.008	0.010	0.014	0.203	0.254	0.356
D	0.815	0.825	0.835	20.701	20.955	21.209
E	0.295	0.300	0.305	7.493	7.620	7.747
e	0.044	0.050	0.056	1.118	1.270	1.422
e_1	0.247	0.267	0.287	6.274	6.782	7.290
He	0.325	0.335	0.345	8.255	8.509	8.763
L	0.080	—	—	2.032	—	—
S	—	—	0.045	—	—	1.143
Y	—	—	0.004	—	—	0.102
q	0	—	10	0°	—	10°

Package Dimensions, continued

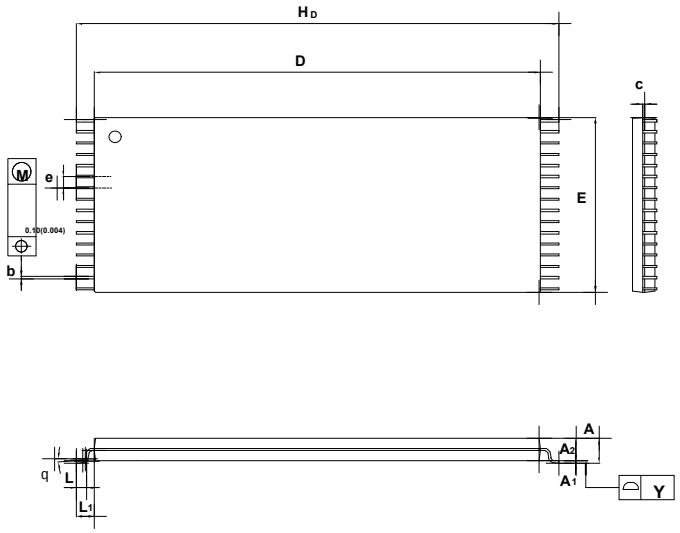
32-pin SOJ (400 mil)



Symbol	Dimension in inches			Dimension in mm		
	Min.	Nom.	Max.	Min.	Nom.	Max.
A	0.131	0.138	0.145	3.33	3.51	3.68
A_1	0.025	—	—	0.635	—	—
A_2	0.105	0.110	0.115	2.67	2.79	2.91
b_1	0.026	0.028	0.032	0.66	0.71	0.81
b	0.016	0.018	0.020	0.41	0.46	0.51
c	0.006	0.008	0.011	0.15	0.20	0.28
D	0.820	0.825	0.830	20.83	20.96	21.08
E	0.395	0.400	0.405	10.03	10.16	10.29
e	0.044	0.050	0.056	1.12	1.27	1.42
e_1	0.360	0.37	0.380	9.15	9.40	9.65
H_E	0.435	0.440	0.445	11.05	11.18	11.31
L	0.082	—	—	2.08	—	—
S	—	—	0.045	—	—	1.14
y	—	—	0.004	—	—	0.10
q	-5°	2°	6°	-5°	2°	6°

Notes:
1. Dimension D Max & S include mold flash or tie bar burrs.
2. Dimension b does not include dambar protrusion/intrusion.
3. Dimension D & E include mold mismatch and are determined at the mold parting line.
4. Controlling dimension: Inches
5. General appearance spec. should be based on final visual inspection spec.

32-pin Standard Type One TSOP



Symbol	Dimension in Inches			Dimension in mm		
	Min.	Nom.	Max.	Min.	Nom.	Max.
A	—	—	0.047	—	—	1.20
A_1	0.002	—	0.006	0.05	—	0.15
A_2	0.037	0.039	0.041	0.95	1.00	1.05
b	0.007	0.008	0.009	0.17	0.20	0.23
c	0.005	0.006	0.007	0.12	0.15	0.17
D	0.720	0.724	0.728	18.30	18.40	18.50
E	0.311	0.315	0.319	7.90	8.00	8.10
H_D	0.780	0.787	0.795	19.80	20.00	20.20
e	—	0.020	—	—	0.50	—
L	0.016	0.020	0.024	0.40	0.50	0.60
L_1	—	0.031	—	—	0.80	—
Y	0.000	—	0.004	0.00	—	0.10
q	1	3	5	1	3	5

Note:
Controlling dimension: Millimeter

Winbond Electronics Corp.

Headquarters

No. 4, Creation Rd. III,
Science-Based Industrial Park,
Hsinchu, Taiwan
TEL: 886-3-5770066
FAX: 886-3-5792647
http://www.winbond.com.tw/
Voice & Fax-on-demand: 886-2-27197006

Taipei Office

11F, No. 115, Sec. 3, Min-Sheng East Rd.,
Taipei, Taiwan
TEL: 886-2-27190505
FAX: 886-2-27197502

Winbond Electronics (H.K.) Ltd.

Rm. 803, World Trade Square, Tower II,
123 Hoi Bun Rd., Kwun Tong,
Kowloon, Hong Kong
TEL: 852-27513100
FAX: 852-27552064

Winbond Electronics North America Corp.
Winbond Memory Lab.
Winbond Microelectronics Corp.
Winbond Systems Lab.

2730 Orchard Parkway, San Jose,
CA 95134, U.S.A.
TEL: 1-408-9436666
FAX: 1-408-9436668